DGG OR DL PACKAGE (TOP VIEW)

SLLS513A - AUGUST 2001 - REVISED MARCH 2004

- Single-Chip and Single-Supply Interface for Two IBM™ PC/AT Serial Ports
- Meet or Exceed the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operate With 3-V to 5.5-V V_{CC} Supply
- Always-Active Noninverting Receiver **Output (ROUT2) Per Port**
- Operate Up To 250 kbit/s
- Low Standby Current . . . 1 µA Typical
- External Capacitors . . . $4 \times 0.22 \mu F$
- Accept 5-V Logic Input With 3.3-V Supply
- Allow for Flexible Power Down of Either **Serial Port**
- **Serial-Mouse Driveability**
- **RS-232 Bus-Pin ESD Protection Exceeds** ±15 kV Using Human-Body Model (HBM)
- **Applications**
 - Battery-Powered Systems, Notebooks, Laptops, Palmtop PCs, and Hand-Held **Equipment**

description/ordering information

The SN65C23243 and SN75C23243 consist of two ports, each containing three line drivers and five line receivers, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port

RIN5A 48 ROUT5A 47 NOUT4A RIN4A II 2 RIN3A [] 3 46 ROUT3A RIN2A 4 45 ∏ ROUT2A RIN1A [15 44 ROUT1A INVA 6 43 ROUT2A DOUT3A Π_7 42 **∏** DIN3A 41 DIN2A DOUT2A 8 DOUT1A [] 9 40 DIN1A FORCEOFFA 1 10 39 T FORCEON 38 N-C2-37 N+ C2+ **∏** 12 GND II 13 36 ∏ C1+ 35 C1-14 Vcc 4 FORCEOFFB [] 15 34 GND DOUT1B 16 33 **∏** DIN1B DOUT2B 1 17 32 DIN2B DOUT3B [] 18 31 DIN3B **INVB 1** 19 30 ROUT2B RIN1B [] 20 29 ROUT1B RIN2B [] 21 28 ROUT2B RIN3B **1**22 27 NOUT3B RIN4B [] 23 26 NOUT4B RIN5B **1**24 25 ∏ ROUT5B

connection pins, including GND). These devices meet the requirements of TIA/EIA-232-F and provide the electrical interface between an asynchronous communication controller and the serial-port connector. This combination of drivers and receivers matches that needed for two typical serial ports used in an IBM PC/AT, or compatible. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. In addition, these devices include an always-active noninverting output (ROUT2) per port, which allows applications using the ring indicator to transmit data while the devices are powered down. The devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/µs driver output slew-rate.

ORDERING INFORMATION

TA	PACKAG	ΕŤ	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	Tube of		SN75C23243DL	75000040
−0°C to 70°C	SSOP (DL)	Reel of 1000	SN75C23243DLR	75C23243
	TSSOP (DGG)	Reel of 2000	SN75C23243DGGR	75C23243
		Tube of 25	SN65C23243DL	05000040
-40°C to 85°C	SSOP (DL)	Reel of 1000	SN65C23243DLR	65C23243
	TSSOP (DGG)	Reel of 2000	SN65C23243DGGR	65C23243

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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description/ordering information (continued)

Flexible control options for power management are available when either or both serial ports are inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs of its respective port are disabled. If FORCEOFF is set low, both drivers and receivers (except ROUT2) are shut off, and the supply current is reduced to 1 µA. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur.

Auto-powerdown can be disabled when FORCEON and FORCEOFF are high and should be done when driving a serial mouse. With auto-powerdown enabled, the RS-232 port is activated automatically when a valid signal is applied to any respective receiver input. The INV output is used to notify the user if an RS-232 signal is present at any receiver input. INV is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V or has been between -0.3 V and 0.3 V for less than 30 μs. INV is low (invalid data) if all receiver input voltages are between –0.3 V and 0.3 V for more than 30 μs. Refer to Figure 5 for receiver input levels.

Function Tables

EACH DRIVER (each port)

		INPUTS		OUTPUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Χ	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
Н	Н	Н	X	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
Н	L	Н	Yes	L	auto-powerdown enabled
L	L	Н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

H = high level, L = low level, X = irrelevant, Z = high impedance

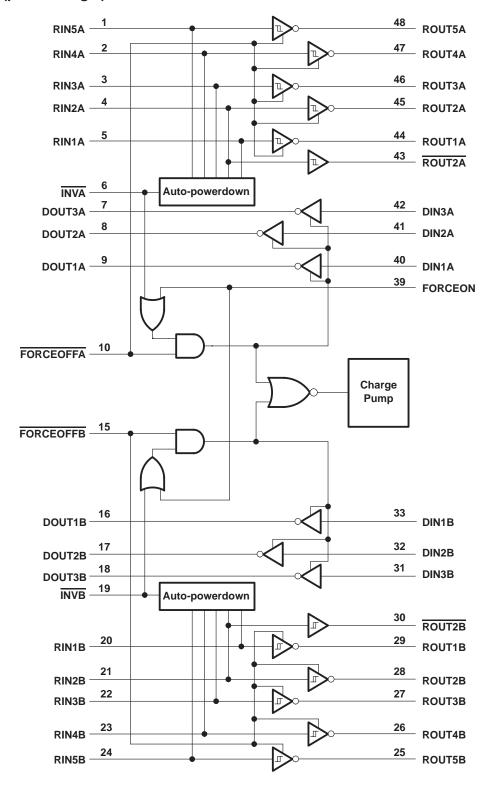
EACH RECEIVER (each port)

			(******	,		
	INPUTS			OUTP	UTS	
RIN2	RIN1, RIN3–RIN5	FORCEOFF	VALID RIN RS-232 LEVEL	ROUT2	ROUT	RECEIVER STATUS
L	Χ	L	Х	L	Z	Powered off while
Н	Χ	L	X	Н	Z	ROUT2 is active
L	L	Н	Yes	L	Н	
L	Н	Н	Yes	L	L	Normal operation with
Н	L	Н	Yes	Н	Н	auto-powerdown
Н	Н	Н	Yes	Н	L	disabled/enabled
Open	Open	Н	No	L	Н	

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

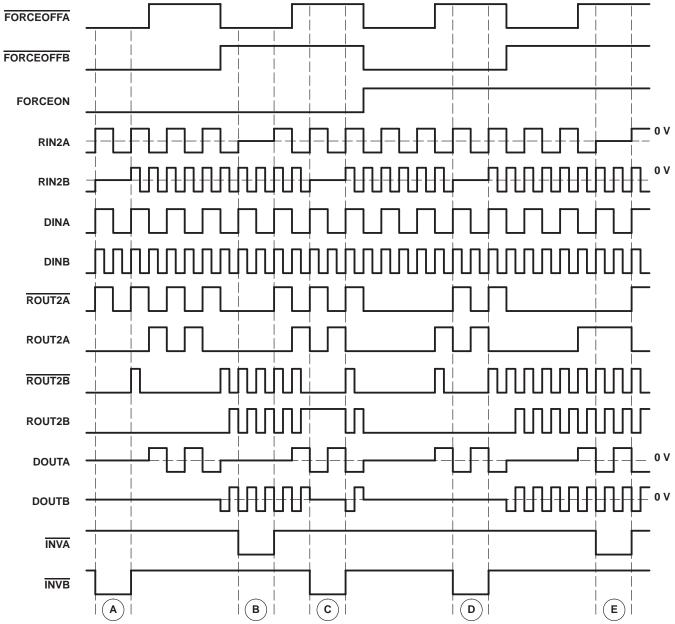


logic diagram (positive logic)



timing

Figure 1 shows how the two independent serial ports can be enabled or disabled. As shown by the logic states, depending on the FORCEOFF, FORCEON, and receiver input levels, either port can be powered down. Intermediate receiver input levels indicate a 0-V input. Also, it is assumed a pulldown resistor to ground is used for the receiver outputs. The INV pin goes low when its respective receiver input does not supply a valid RS-232 level. For simplicity, voltage levels, timing differences, and input/output edge rates are not shown.



NOTES: A. Ports A and B manually powered off

- B. Port A manually powered off, port B in normal operation with auto-powerdown enabled
- C. Port B powered off by auto-powerdown, port A in normal operation with auto-powerdown enabled
- D. Port A in normal operation with auto-powerdown disabled, port B manually powered off
- E. Ports A and B in normal operation with auto-powerdown disabled

Figure 1. Timing Diagram



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)	–0.3 V to 6 V
Positive output supply voltage range, V+ (see Note 1)	–0.3 V to 7 V
Negative output supply voltage, V– (see Note 1)	0.3 V to –7 V
Supply voltage difference, V+ – V– (see Note 1)	
Input voltage range, V _I : Driver (FORCEOFF, FORCEON)	0.3 V to 6 V
Receiver	–25 V to 25 V
Output voltage range, V _O : Driver	13.2 V to 13.2 V
Receiver (INV)	0.3 V to V _{CC} + 0.3 V
Package thermal impedance, θ _{JA} (see Notes 2 and 3): DGG package	
DL package	63°C/W
Operating virtual junction temperature, T _J	150°C
Storage temperature range, T _{stq}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to network GND.
 - 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4 and Figure 7)

			MIN	NOM	MAX	UNIT
Ownskippe	unnly voltage		3	3.3	3.6	
Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	>
Division and accepted blink level linear trade and M	VILL DIN FORCEOFF FORCEON	V _{CC} = 3.3 V	2			
Driver and control high-level input voltage, V _{IH}		$V_{CC} = 5 V$	2.4			V
Driver and control low-level input voltage, V _{IL}	DIN, FORCEOFF, FORCEON				0.8	V
Driver and control input voltage, V _I	DIN, FORCEOFF, FORCEON		0		5.5	V
Receiver input voltage, V _I	RIN		-25		25	V
		SN75C23243	0		70	00
Operating free-air temperature, T _A		SN65C23243	-40		85	°C

NOTE 4: Test conditions are C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 7)

	PARAME	TER	TEST CONDITIONS	MIN	TYP‡	MAX	UNIT
П	Input leakage current	FORCEOFF, FORCEON			±0.01	±1	μΑ
		Auto-powerdown disabled	No load, FORCEOFF and FORCEON at V _{CC}		0.6	2	mA
Icc	Supply current	Powered off	No load, FORCEOFF at GND		1	20	
	(T _A = 25°C)	Auto-powerdown enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	20	μΑ

[‡] All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

NOTE 4: Test conditions are C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.



DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 7)

	PARAMETER	TE	ST CONDITION	S	MIN	TYP [†]	MAX	UNIT
Vон	High-level output voltage	All DOUT at $R_L = 3 \text{ k}\Omega$ to	All DOUT at R _L = 3 k Ω to GND		5	5.4		V
VOL	Low-level output voltage	All DOUT at $R_L = 3 \text{ k}\Omega$ to	All DOUT at R _L = $3 \text{ k}\Omega$ to GND		-5	-5.4		V
VO	Output voltage (mouse driveability)		DIN1 = DIN2 = GND, DIN3 = V_{CC} , - $k\Omega$ to GND at DOUT3, DOUT1 = DOUT2 = -2.5 mA		±5			V
lіН	High-level input current	$V_I = V_{CC}$				±0.01	±1	μΑ
Ι _Ι Γ	Low-level input current	V _I at GND				±0.01	±1	μΑ
		VCC = 3.6 V,	VO = 0 V					
los	Short-circuit output current‡	V _{CC} = 5.5 V,	VO = 0 V			±35	±60	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	V _O = ±2 V		300	10M		Ω
	Output lackage current	FORCEOFF = GND	$V_0 = \pm 12 V$,	$V_{CC} = 3 V \text{ to } 3.6 V$			±25	^
loff	Output leakage current	FURGEOFF = GND	$V_0 = \pm 10 \text{ V},$	V _{CC} = 4.5 V to 5.5 V			±25	μΑ

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 7)

	PARAMETER	TEST CONDITIONS			TYP†	MAX	UNIT
	Maximum data rate	C _L = 1000 pF, One DOUT switching,	$R_L = 3 k\Omega$, See Figure 1	250			kbit/s
tsk(p)	Pulse skew§	C _L = 150 pF to 2500 pF	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$ See Figure 2		100		ns
SR(tr)	Slew rate, transition region	V _{CC} = 3.3 V,	C _L = 150 pF to 1000 pF	6		30	V/µs
SK(II)	(see Figure 1)	$R_L = 3 k\Omega$ to $7 k\Omega$	C _L = 150 pF to 2500 pF	4		30	ν/μδ

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

§ Pulse skew is defined as $|tp_{LH} - tp_{HL}|$ of each channel of the same device. NOTE 4: Test conditions are C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



^{\$\}frac{1}{2}\$ Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

NOTE 4: Test conditions are C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 7)

	PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
Vон	High-level output voltage	I _{OH} = -1 mA	V _{CC} – 0.6 V	V _{CC} – 0.1 V		V
VOL	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
.,	Partition and an investment through a behavior	VCC = 3.3 V		1.6	2.4	.,
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 5 V		1.9	2.4	V
.,	Manager and a Constitutional and college	V _{CC} = 3.3 V	0.6	1.1		
V _{IT} _	Negative-going input threshold voltage	V _{CC} = 5 V	0.8	1.4		V
V _{hys}	Input hysteresis (V _{IT+} – V _{IT} _)			0.5		V
l _{off}	Output leakage current (except ROUT2B)	FORCEOFF = 0 V		±0.05	±10	μΑ
rį	Input resistance	$V_{I} = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

 $[\]overline{\dagger}$ All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V and T_A = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.22 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 7)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output	C _L = 150 pF, See Figure 4		150		ns
tPHL	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 4		150		ns
t _{en}	Output enable time	0 450 5 0 0 0 0 5 5 5 5		200		ns
t _{dis}	Output disable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{See Figure 5}$		200		ns
t _{sk(p)}	Pulse skew [‡]	See Figure 4		50		ns

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

‡ Pulse skew is defined as $|tp_{LH} - tp_{HL}|$ of each channel of the same device. NOTE 4: Test conditions are C1–C4 = 0.22 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



AUTO-POWERDOWN SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
VT+(valid)	Receiver input threshold for INV high-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}		2.7	V
VT-(valid)	Receiver input threshold for INV high-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}	-2.7		V
VT(invalid)	Receiver input threshold for INV low-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}	-0.3	0.3	V
VOH	INV high-level output voltage	I _{OH} = -1 mA, FORCEON = GND, FORCEOFF = V _{CC}	V _{CC} - 0.6		٧
V _{OL}	INV low-level output voltage	I _{OL} = 1.6 mA, FORCEON = GND, FORCEOFF = V _{CC}		0.4	V

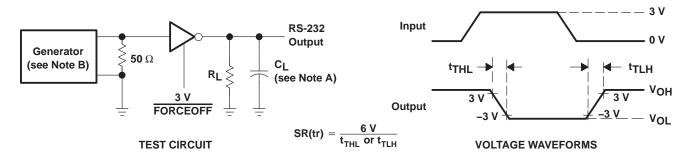
switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER MIN TYPT MAX				UNIT
^t valid	Propagation delay time, low- to high-level output		1		μs
tinvalid	Propagation delay time, high- to low-level output		30		μs
ten	Supply enable time		100		μs

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V and T_A = 25°C.



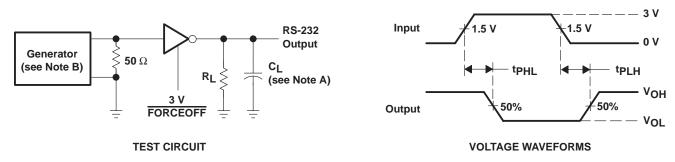
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

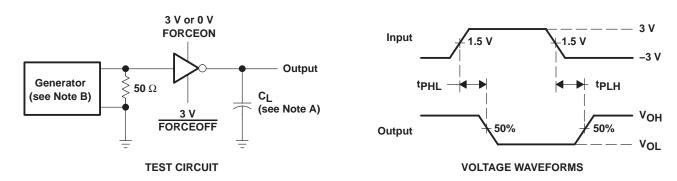
Figure 2. Driver Slew Rate



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_Q = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 3. Driver Pulse Skew



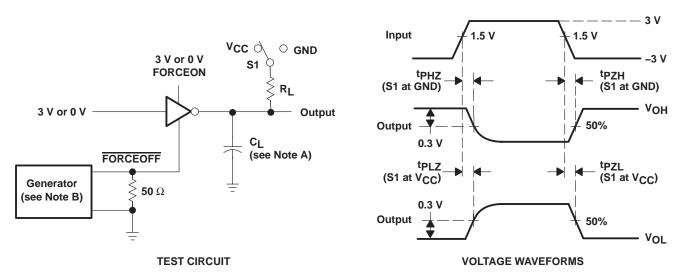
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \ \Omega$, 50% duty cycle, $t_r \le 10 \ ns$, $t_f \le 10 \ ns$.

Figure 4. Receiver Propagation Delay Times



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

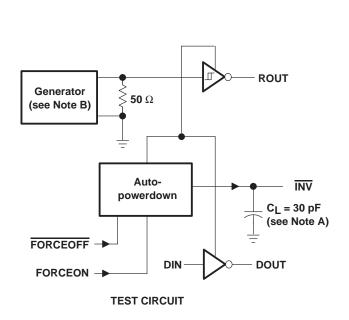
B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

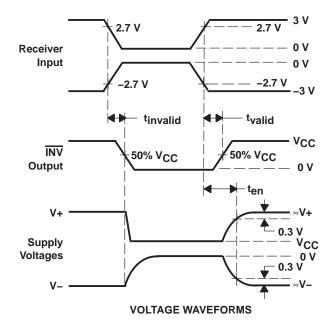
C. tpLz and tpHz are the same as tdis.

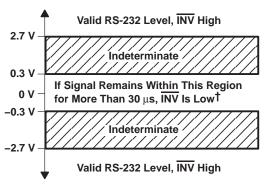
D. tpZL and tpZH are the same as ten.

Figure 5. Receiver Enable and Disable Times

PARAMETER MEASUREMENT INFORMATION







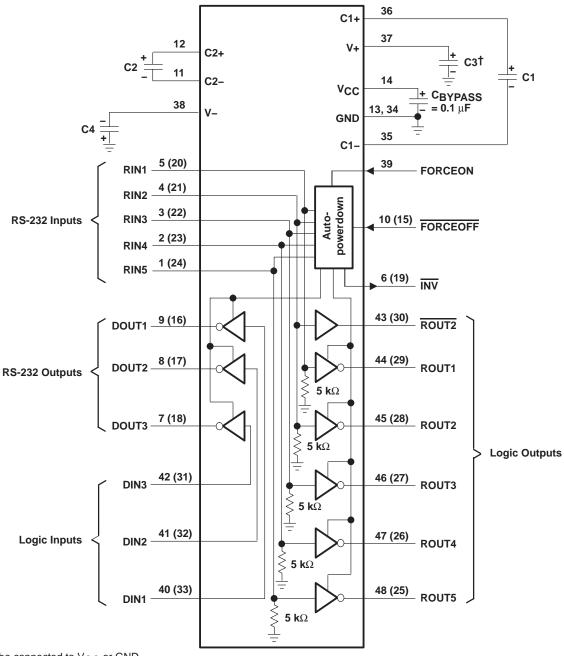
 † Auto-powerdown disables drivers and reduces supply current to 1 $\mu A.$

NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_\Gamma \le 10$ ns. $t_f \le 10$ ns.

Figure 6. INV Propagation Delay Times and Supply Enabling Time

APPLICATION INFORMATION



 $\ensuremath{^{\dagger}}\xspace \text{C3}$ can be connected to $\ensuremath{\text{V}_{CC}}\xspace$ or GND.

NOTES: A. Resistor values shown are nominal.

B. Numbers in parentheses are for B section.

V_{CC} vs CAPACITOR VALUES

VCC	C1	C2, C3, and C4
$3.3~\text{V}\pm0.3~\text{V}$ $5~\text{V}\pm0.5~\text{V}$ $3~\text{V}$ to $5.5~\text{V}$	0.22 μF 0.047 μF 0.22 μF	0.22 μF 0.33 μF 1 μF

Figure 7. Typical Operating Circuit and Capacitor Values







i.com 24-Feb-2006

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN65C23243DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C23243DGGRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C23243DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C23243DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C23243DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C23243DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C23243DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C23243DGGRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C23243DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C23243DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C23243DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C23243DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

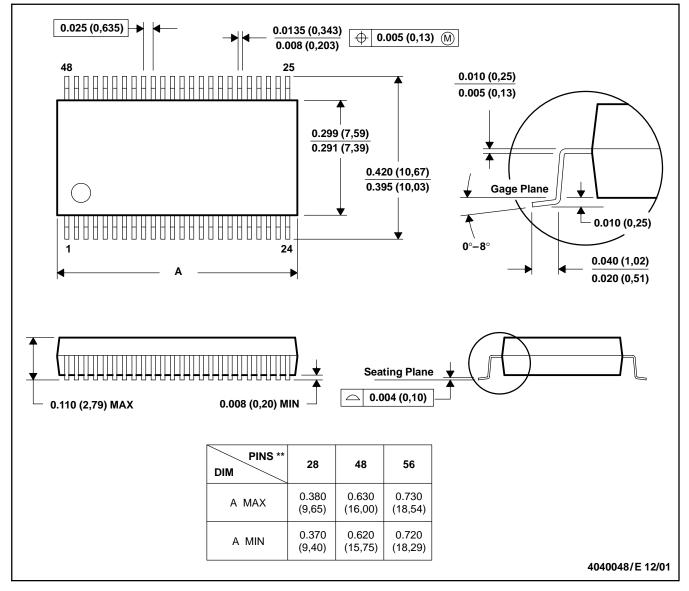
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DL (R-PDSO-G**)

48 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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